Docket No.: 42P17681

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re the Application of:

HAI DENG, ET AL.

Application No.:

Filed:

For: ZEOLITE - CARBON DOPED OXIDE COMPOSITE LOW K DIELECTRIC

Art Group:

Examiner:

## INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

In accordance with the duty of disclosure, enclosed is a copy of Information Disclosure Statement by Applicant (form PTO/SB/08), which is being submitted concurrently with the Utility Application. It is respectfully requested that the cited references be considered and that the enclosed copy of PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s). Copies of the references cited on PTO/SB/08 are enclosed herewith.

-1-

The submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made in the subject application and is not to be construed as an admission that the information cited in this statement is material to patentability.

Please charge any fees due to Deposit Account 02-2666. A duplicate copy of the Fee Transmittal (PTO/SB/17) is enclosed for this purpose.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

Edwin H. Taylor, Reg. No. 25,129

1279 Oakmead Parkway Sunnyvale, CA 94085

Telephone: (408) 720-8300

I hereby certify that this correspondence is being deposited with the United States Postal Service on the date shown below with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Patricia M Richard

Date

Substitute for form 1449A/PTO				Complete if Known		
INFORMATION DISCLOSURE			OUDE	Application Number		
INFOR	MATION L	JISCLC	SURE	Filing Date		
STATE	MENT BY	ΔΡΡΙ Ι	CANT	First Named Inventor	Hai Deng	
				Art Unit		
(use as many sheets as necessary)			• • • • • • • • • • • • • • • • • • • •	Examiner Name		
Sheet	1	of	2	Attorney Docket Number	42P17681	

U.S. PATENT DOCUMENTS						
		Document Number	Publication Date		Pages, Columns, Lines, Where	
Examiner Initials*	Cite No.¹	Number - Kind Code <sup>2</sup> (if known)	or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Relevant Passages or Relevant Figures Appear	
		US-6,573,131 B2	06-03-2003	Yan, et al.		
		US-				
		US-				
		US-				
		US-				
		US-				
		US-				
		US-				
		US-				
		US-				
		US-				
		US-				
		US-		·		
		US-				
		US-				
		US-				
		US-				
		US-				
		US-				
		US-				

FOREIGN PATENT DOCUMENTS								
Examiner Cite	Foreign Patent Document			Pages, Columns, Lines,	T.			
Initials*		Country Code <sup>3</sup> - Number <sup>4</sup> - Kind Code <sup>5</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Where Relevant Passages or Relevant Figures Appear			
			_					
						Γ		
				·				

Examiner	Date	
Signature	Considered	

<sup>\*</sup>Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

<sup>&#</sup>x27;Applicant's unique citation designation number (optional). <sup>3</sup>See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. <sup>3</sup>Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup>For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. <sup>4</sup>Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>4</sup>Applicant is to place a check mark here if English language Translation is attached.

Substitute for form 1449A/PTO				Complete If Known		
INFORMATION DISCLOSURE			CHDE	Application Number		
			SURE	Filing Date		
STATEMENT BY APPLICANT				First Named Inventor	Hai Deng	
·			<i>-</i> ,	Art Unit		
				Examiner Name		
Sheet	2	of	2	Attorney Docket Number	42P17681	

NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No.¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²		
		MORRIS, et al. METHOD OF FABRICATION OF LOW DIELECTRIC CONSTANT POROUS METAL SILICATE FILMS, U.S. Patent Application No. 10/323,988, Filed 12/17/2002, 23 pages.			
		ZHENGBAO WANG, et al., Pure Silica Zeolite Films as Low-k Dielectrics by Spin-On of Nanoparticle Suspensions, Advanced Materials 2001, No. 19, October 2, pp.1463-1466			
		ZHENGBAO WANG, et al., Silica Zeolite Low-k Dielectric Films, Department of Chemical and Environmental Engineering, University of California, Riverside, 15 pages.			
			.7		
			:		
		·			
			:		
		·	:		
			:		

Examiner		Date	
Signature		Considered	

<sup>\*</sup>Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

<sup>&#</sup>x27;Applicant's unique citation designation number. 'Applicant is to place a check mark here if English language Translation is attached.